

SV-QSFP-400G-CLR4

Starview QSFP56-DD 400G-LR4
aggregating 4 x 100Gbps CWDM SM (LC)
with DDM, distance up to 10km



Features

- Supports 425Gbps
- Single 3.3V Power Supply
- Power dissipation < 10W
- Up to 10km over SMF
- RoHS compliant
- QSFP-DD MSA Compliant
- 8x53.125Gbps (PAM4) electrical interface
- Duplex LC connector
- Commercial case temperature range of 0°C to 70°C
- PIN and TIA array on the receiver side
- I2C interface with integrated Digital Diagnostic Monitoring
- Safety Certification: TUV/UL/FDA

Applications

- 400G-LR4-10 applications
- Data center
- Enterprise networking
- Infiniband interconnects

Part number	Description
SV-QSFP-400G-CLR4	Starview QSFP56-DD 400Gbps module 400G-LR4 aggregating 4 x 100Gbps CWDM (1271/1291/1311/1331nm) SM (LC) with Digital Diagnostic Monitoring (DDM), distance up to 10km

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit
Storage Temperature	Ts	-40	+85	°C
Supply Voltage	Vcc	-0.5	3.6	V
Damage threshold	Rxdmg	6.6		dBm

Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Max	Unit
Operating case temperature	Tc	0		70	°C
Power supply voltage	Vcc	3.135	3.3	3.465	V
Operating relative humidity	RH	5		85	%
Powerdissipation	High power	P _d		10	W
	Low power	P _d		1.5	W

* Power Supply specifications, Instantaneous, sustained and steady state current compliant with QSFP-DD MSA Power Classification.

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max	Unit	Notes
Transmitter						
Differential data input swing per lane*(note5)		900			mV _{p-p}	
Differential input impedance	Z _{in}	90	100	110	ohm	
Stressed input parameters						
Eye width		0.265			UI	@TP4, all 3 PAM4 eyes, 1E-5
DC common mode voltage*(note6)		-350		2850	mV	
Receiver						
Differential output amplitude				900	mV _{p-p}	
Differential output impedance	Z _{out}	90	100	110	ohm	
Output Rise/Fall Time	t _r /t _f	9.5			ps	20%~80%
Eye width		0.265			UI	
Eye height differential		70			mV	@TP4, all 3 PAM4 eyes, 1E-5

Note5: With the exception to IEEE 802.3bs 120E.3.1.2 that the pattern is PRBS31Q or scrambled idle.

Note6: DC common mode voltage is generated by the host. Specification includes effects of ground offset voltage.

Optical Characteristics

Parameter	Symbol	Min	Typical	Max	Unit
Transmitter					
Signaling speed per lane			53.125±100 ppm		GBd
Modulation format			PA M4		
Lane_0 Center Wavelength	λ_{c0}	1264.5		1277.5	nm
Lane_1 Center Wavelength	λ_{c1}	1284.5		1297.5	nm
Lane_2 Center Wavelength	λ_{c2}	1304.5		1317.5	nm
Lane_3 Center Wavelength	λ_{c3}	1324.5		1337.5	nm
Side-mode Suppression Ratio	SMSR	30			dB
Total average launch power				11.6	dBm
Average launch power, each lane*(note7)	TxAVG	-2.8		5.6	dBm
Outer Optical Modulation Amplitude (OMA _{outer}), each lane*(note8)	TxOMA	0.2		4.4	dBm
Difference in launch power between any two lanes (OMA _{outer})				4	dB
Launch power in OMA _{outer} minus TDECQ, each lane for ER ≥ 4.5 dB	OMA _{outer}				dBm
ER < 4.5 dB	-TDECQ	-1.2			
		-1.1			
Transmitter and dispersion eye closure for PAM4, each lane	TDECQ			3.9	dB
TDECQ-10*log ₁₀ (Ceq), each lane*(note9)				3.9	dB
Average launch power of OFF transmitter, each lane				-16	dBm
Extinction Ratio, each lane	ER	3.5			dB
Transmitter transition time				17	ps
RIN _{15.6} OMA				-136	dB/Hz
Optical return loss tolerance				15.6	dB
Transmitter reflectance*(note10)	Txref			-26	dB
Receiver					
Signaling speed per lane			53.125±100 ppm		GBd
Lane_0 Center Wavelength	λ_{c0}	1264.5		1277.5	nm
Lane_1 Center Wavelength	λ_{c1}	1284.5		1297.5	nm
Lane_2 Center Wavelength	λ_{c2}	1304.5		1317.5	nm
Lane_3 Center Wavelength	λ_{c3}	1324.5		1337.5	nm
Damage threshold each lane*(note11)		6.6			dBm

Average receive power each lane*(note12)	RxAVG	-9.1	5.6	dBm
Receive Power (OMA _{outer}) each lane	RxOMA		4.4	dBm
Difference in receive power between any two lanes (OMA _{outer})			4.3	dB
Receiver reflectance			-26	dB
Receiver sensitivity (OMA _{outer}), each lane*(note13)	SenOMA		Max(-6.8, SECQ-8.2)	dBm
Stressed receiver sensitivity (OMA _{outer}), each lane*(note14)			-4.3	dBm
Conditions of stressed receiver sensitivity test:				
Stressed eye closure for PAM4 (SECQ), lane under test			3.9	dB
SECQ – 10*log ₁₀ (Ceq), lane under test*(note9)			3.9	dB
OMA _{outer} of each aggressor lane			-0.4	dBm
LOS Assert	LOSA	-15		dBm
LOS De-Assert	LOSD		-10	dBm
LOS Hysteresis	LOSH	0.5		dB

Note7: Average launch power, each lane (min) is informative and not the principal indicator of signal strength. A transmitter with launch power below this value cannot be compliant; however, a value above this does not ensure compliance.

Note8: Even if the TDECQ < 1.4 dB for an extinction ratio of ≥ 4.5 dB or TDECQ < 1.3 dB for an extinction ratio of < 4.5 dB, the OMA_{outer} (min) must exceed this value.

Note9: Ceq is a coefficient defined in IEEE Std 802.3-2018 clause 121.8.5.3 which accounts for reference equalizer noise enhancement.

Note10: Transmitter reflectance is defined looking into the transmitter.

Note11: The receiver shall be able to tolerate, without damage, continuous exposure to an optical input signal having this average power level. The receiver does not have to operate correctly at this input power.

Note12: Average receive power, each lane (min) is informative and not the principal indicator of signal strength. A received power below this value cannot be compliant; however, a value above this does not ensure compliance.

Note13: For 400G-LR4-10, Receiver sensitivity (OMA_{outer}), each lane (max) is informative and is defined for a transmitter with a value of SECQ up to 3.9dB. Receiver sensitivity should meet the following equation. RS = max (-6.8, SECQ-8.2) dBm

Note14: Measured with conformance test signal at TP3 (see Clause 151.8.11 of IEEE P802.3cu) for the BER specified in ROG.080 and in Clause 151.1.1 of IEEE P802.3cu.